

**描述 / Descriptions**

TO-126F(R)塑封封装 NPN 半导体三极管。Silicon NPN transistor in a TO-126F(R) Plastic Package.

**特征 / Features**

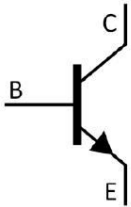
耐压高，快速转换。

High Voltage Capability High Speed Switching.

**用途 / Applications**

主要用于节能灯、日光灯电子镇流器及其它开关、振荡电路。

High frequency electronic lighting ballast applications,converters, inverters, switching regulators, etc.

**内部等效电路 / Equivalent Circuit****引脚排列 / Pinning**

PIN1 : Base      PIN 2 : Collector      PIN 3 : Emitter

**放大及印章代码 /  $h_{FE}$  Classifications & Marking**

见印章说明      See Marking Instructions.

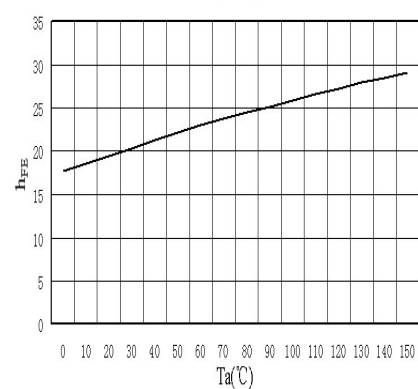
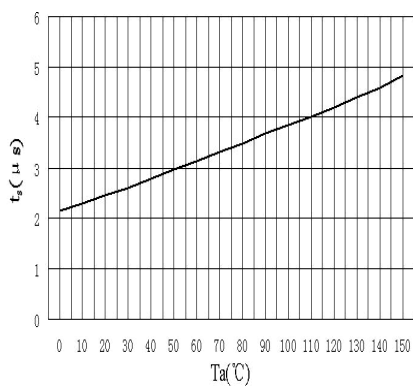
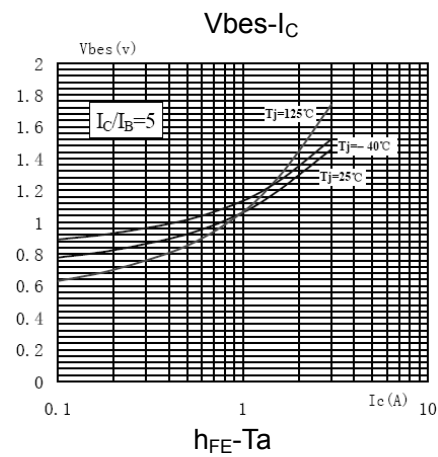
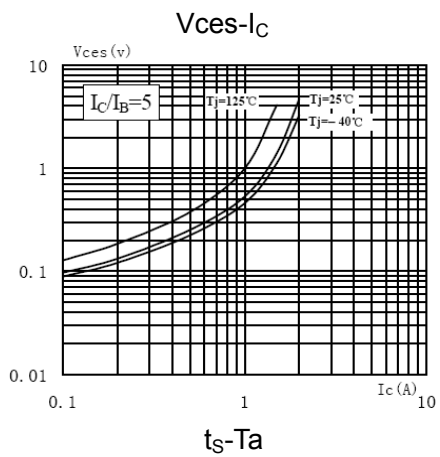
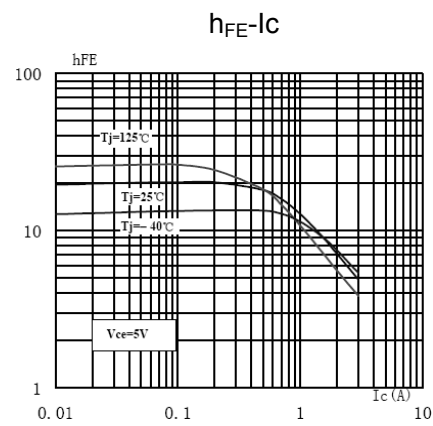
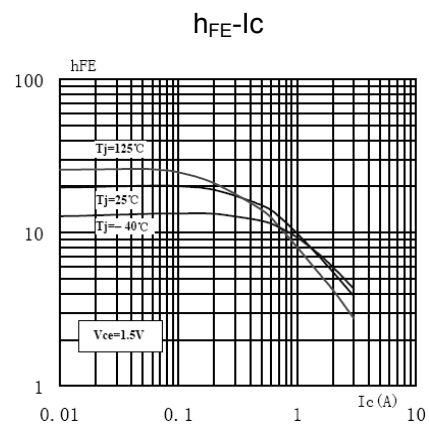
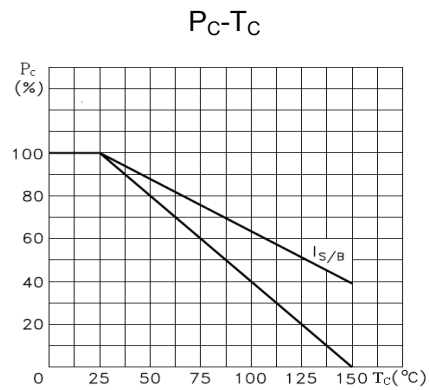
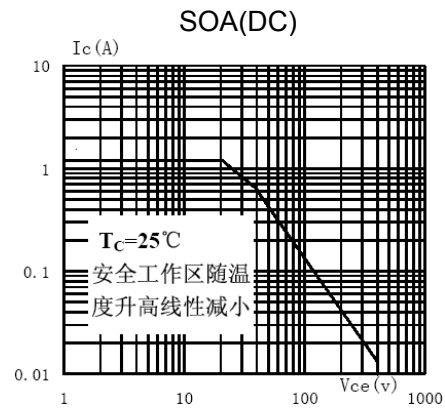

**极限参数 / Absolute Maximum Ratings(Ta=25°C)**

| 参数<br>Parameter                | 符号<br>Symbol                  | 数值<br>Rating | 单位<br>Unit         |
|--------------------------------|-------------------------------|--------------|--------------------|
| Collector to Base Voltage      | $V_{CBO}$                     | 600          | V                  |
| Collector to Emitter Voltage   | $V_{CEO}$                     | 400          | V                  |
| Emitter to Base Voltage        | $V_{EBO}$                     | 9.0          | V                  |
| Collector Current - Continuous | $I_C$                         | 1.2          | A                  |
| Collector Power Dissipation    | $P_C$                         | 1.25         | W                  |
| Collector Power Dissipation    | $P_C(T_c=25^{\circ}\text{C})$ | 40           | W                  |
| Junction Temperature           | $T_j$                         | 150          | $^{\circ}\text{C}$ |
| Storage Temperature Range      | $T_{stg}$                     | -55~150      | $^{\circ}\text{C}$ |

**电性能参数 / Electrical Characteristics(Ta=25°C)**

| 参数<br>Parameter                         | 符号<br>Symbol  | 测试条件<br>Test Conditions                                     | 最小值<br>Min | 典型值<br>Typ | 最大值<br>Max | 单位<br>Unit    |
|-----------------------------------------|---------------|-------------------------------------------------------------|------------|------------|------------|---------------|
| Collector to Base Breakdown Voltage     | $V_{CBO}$     | $I_C=1\text{mA}$ $I_E=0$                                    | 600        |            |            | V             |
| Collector to Emitter Breakdown Voltage  | $V_{CEO}$     | $I_C=10\text{mA}$ $I_B=0$                                   | 400        |            |            | V             |
| Emitter to Base Breakdown Voltage       | $V_{EBO}$     | $I_E=1\text{mA}$ $I_C=0$                                    | 9.0        |            |            | V             |
| Collector Cut-Off Current               | $I_{CBO}$     | $V_{CB}=600\text{V}$ $I_E=0$                                |            |            | 0.1        | mA            |
| Collector cut-off current               | $I_{CEO}$     | $V_{CE}=400\text{V}$ $I_B=0$                                |            |            | 0.1        | mA            |
| Emitter Base Cut-Off Current            | $I_{EBO}$     | $V_{EB}=9.0\text{V}$ $I_C=0$                                |            |            | 0.1        | mA            |
| DC Current Gain                         | $h_{FE}$      | $V_{CE}=5.0\text{V}$ $I_C=200\text{mA}$                     | 10         |            | 40         |               |
| Collector to Emitter Saturation Voltage | $V_{CE(sat)}$ | $I_C=500\text{mA}$ $I_B=100\text{mA}$                       |            |            | 0.8        | V             |
| Base to Emitter Saturation Voltage      | $V_{BE(sat)}$ | $I_C=500\text{mA}$ $I_B=100\text{mA}$                       |            |            | 1.2        | V             |
| Transition Frequency                    | $f_T$         | $V_{CE}=10\text{V}$ $I_C=100\text{mA}$<br>$f=1.0\text{MHz}$ | 5.0        |            |            | MHz           |
| Fall time                               | $t_f$         | $V_{CE}=5\text{V}$ $I_C=250\text{mA}$<br>(UI9600)           |            |            | 0.6        | $\mu\text{s}$ |
| Storage time                            | $t_s$         |                                                             |            |            | 3.5        | $\mu\text{s}$ |

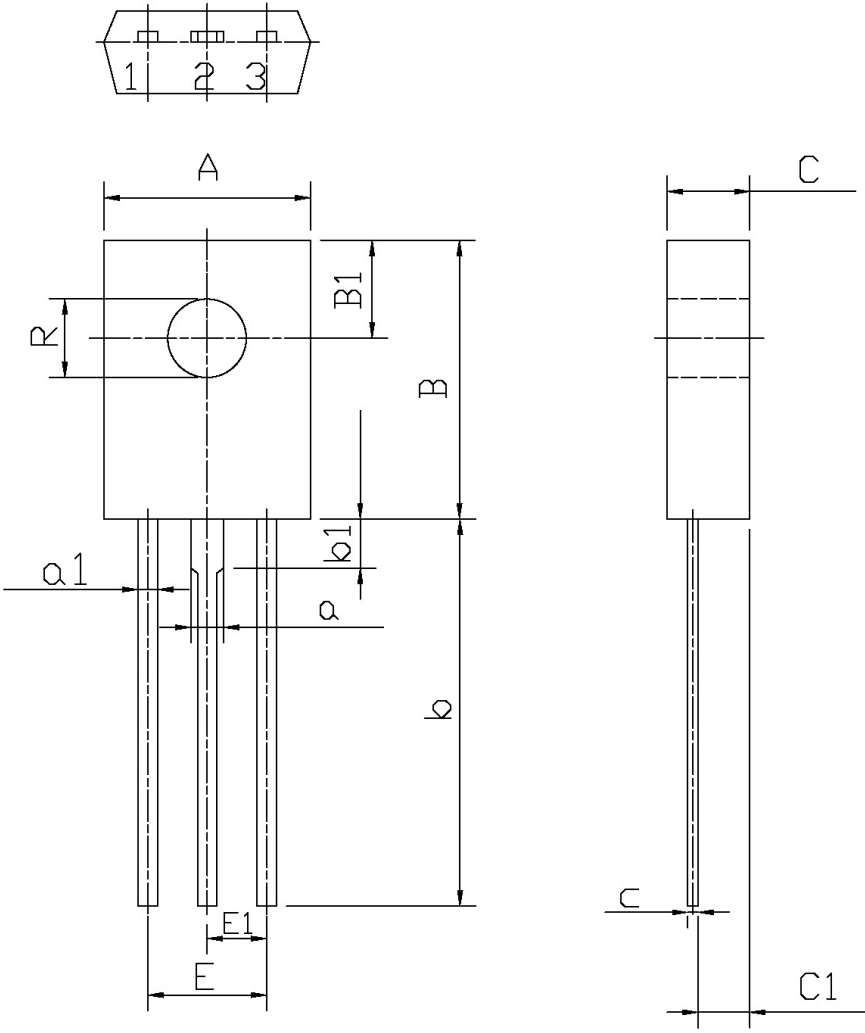
## 电参数曲线图 / Electrical Characteristic Curve



外形尺寸图 / Package Dimensions

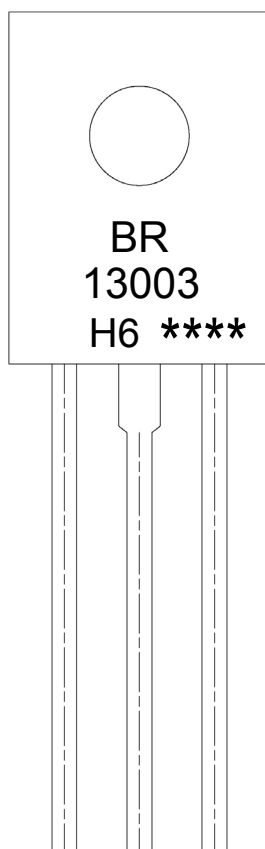
T□-126F(R)

单位: mm



| Symbol | Dimensions In Millimeters |      | Symbol | Dimensions In Millimeters |      |
|--------|---------------------------|------|--------|---------------------------|------|
|        | Min                       | Max  |        | Min                       | Max  |
| A      | 7.8                       | 8.2  | a1     | 0.66                      | 0.86 |
| B      | 10.8                      | 11.2 | E      | 4.4                       | 4.8  |
| B1     | 3.8                       | 4.2  | C      | 3.1                       | 3.3  |
| R      | 2.95                      | 3.15 | C1     | 1.9                       | 2.1  |
| b      | 14                        | 16   | c      | 0.3                       | 0.6  |
| b1     | 1.9                       |      | a      | 1.27                      |      |
| E1     | 2.1                       | 2.5  |        |                           |      |

印章说明 / Marking Instructions



说明：

BR： 为公司代码

13003： 为型号代码

H6: 为规格代码

\*\*\*\*： 为生产批号代码，随生产批号变化。

Note:

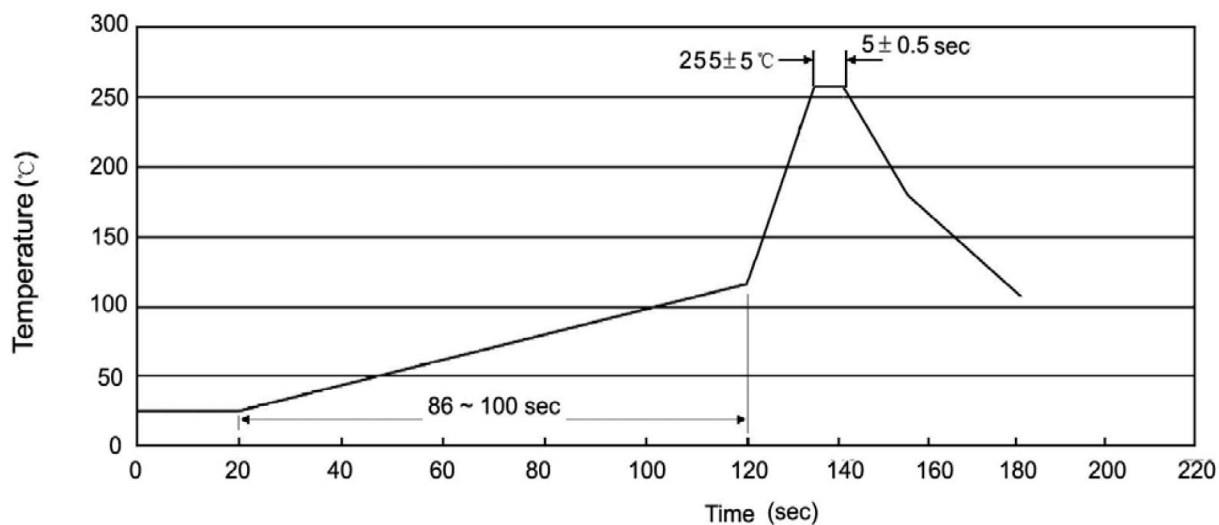
BR: Company Code

13003: Product Type.

H6: Specification Code.

\*\*\*\*: Lot No. Code, code change with Lot No.

## 波峰焊温度曲线图(无铅) / Temperature Profile for Dip Soldering(Pb-Free)



说明：

- 1、预热温度 25~150°C，时间 60~90sec;
- 2、峰值温度 255±5°C，时间持续为 5±0.5sec;
- 3、焊接制程冷却速度为 2~10°C/sec.

Note:

- 1.Preheating:25~150°C, Time:60~90sec.
- 2.Peak Temp.:255±5°C, Duration:5±0.5sec.
3. Cooling Speed: 2~10°C/sec.

## 耐焊接热试验条件 / Resistance to Soldering Heat Test Conditions

温度：270±5°C

时间：10±1 sec.

Temp.:270±5°C

Time:10±1 sec

## 包装规格 / Packaging SPEC.

散件包装 / BULK

| Package Type<br>封装形式 | Units 包装数量         |                         |                        |                              |                        | Dimension 包装尺寸 (unit: mm <sup>3</sup> ) |             |             |
|----------------------|--------------------|-------------------------|------------------------|------------------------------|------------------------|-----------------------------------------|-------------|-------------|
|                      | Units/Tube<br>只/套管 | Tubes/Inner Box<br>套管/盒 | Units/Inner Box<br>只/盒 | Inner Boxes/Outer Box<br>盒/箱 | Units/Outer Box<br>只/箱 | Tube 套管                                 | Inner Box 盒 | Outer Box 箱 |
| TO-126/F             | 500                | 6                       | 3,000                  | 5                            | 15,000                 | 135×190                                 | 237×172×102 | 560×245×195 |

套管包装 / TUBE

| Package Type<br>封装形式 | Units 包装数量         |                         |                        |                              |                        | Dimension 包装尺寸 (unit: mm <sup>3</sup> ) |             |             |
|----------------------|--------------------|-------------------------|------------------------|------------------------------|------------------------|-----------------------------------------|-------------|-------------|
|                      | Units/Tube<br>只/套管 | Tubes/Inner Box<br>套管/盒 | Units/Inner Box<br>只/盒 | Inner Boxes/Outer Box<br>盒/箱 | Units/Outer Box<br>只/箱 | Tube 套管                                 | Inner Box 盒 | Outer Box 箱 |
| TO-126/F             | 65                 | 26                      | 1,690                  | 5                            | 8,450                  | 532×31×5.6                              | 555×164×50  | 575×290×180 |

## 使用说明 / Notices